

December 1992

## Features

- High Voltage Types (20V Rating)
- Schmitt Trigger Action on Each Input With No External Components
- Hysteresis Voltage Typically 0.9V at VDD = 5V and 2.3V at VDD = 10V
- Noise Immunity Greater than 50%
- No Limit on Input Rise and Fall Times
- Standardized, Symmetrical Output Characteristics
- 100% Tested for Quiescent Current at 20V
- Maximum Input Current of 1 $\mu$ A at 18V Over Full Package Temperature Range, 100nA at 18V and +25°C
- 5V, 10V and 15V Parametric Ratings
- Meets All Requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

## Applications

- Wave and Pulse Shapers
- High Noise Environment Systems
- Monostable Multivibrators
- Astable Multivibrators
- NAND Logic

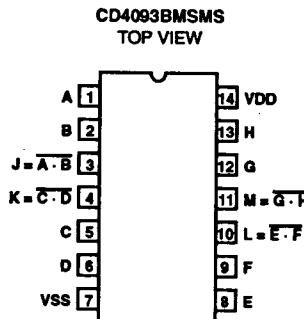
## Description

CD4093BMS consists of four Schmitt trigger circuits. Each circuit functions as a two input NAND gate with Schmitt trigger action on both inputs. The gate switches at different points for positive and negative going signals. The difference between the positive voltage (VP) and the negative voltage (VN) is defined as hysteresis voltage (VH) (see Figure 1).

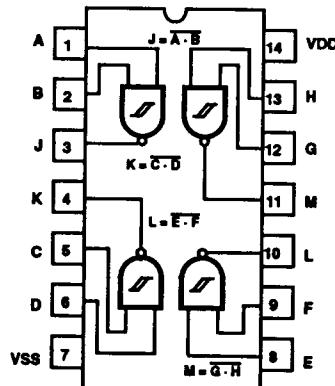
The CD4093BMS is supplied in these 14 lead outline packages:

|                  |     |
|------------------|-----|
| Braze Seal DIP   | H4H |
| Frit Seal DIP    | H1B |
| Ceramic Flatpack | H3W |

## Pinout



## Functional Diagram



## **Specifications CD4093BMS**

### Absolute Maximum Ratings

|   |                    |
|---|--------------------|
| DC Supply Voltage Range, (VDD) . . . . .                                    | -0.5V to +20V      |
| (Voltage Referenced to VSS Terminals)                                       |                    |
| Input Voltage Range, All Inputs . . . . .                                   | -0.5V to VDD +0.5V |
| DC Input Current, Any One Input. . . . .                                    | ±10mA              |
| Operating Temperature Range . . . . .                                       | -55°C to +125°C    |
| Package Types D, F, K, H  |                    |
| Storage Temperature Range (TSTG) . . . . .                                  | -65°C to +150°C    |
| Lead Temperature (During Soldering) . . . . .                               | +265°C             |
| At Distance 1/16 ± 1/32 Inch (1.59mm ± 0.79mm) from case for<br>10s Maximum |                    |

## **Reliability Information**

|   |             |   |               |
|---|-------------|---|---------------|
| <b>Thermal Resistance</b>                                   | .....       | $\theta_{ja}$                           | $\theta_{jc}$ |
| Ceramic DIP and FRIT Package                                | .....       | 80°C/W                                  | 20°C/W        |
| Flatpack Package  | .....       | 70°C/W                                  | 20°C/W        |
| <b>Maximum Package Power Dissipation (PD)</b>               | (at +125°C) |   |               |
| For TA = -55°C to +100°C (Package Type D, F, K)             | .....       | 500mW                                   |               |
| For TA = +100°C to +125°C (Package Type D, F, K)            | .....       | Derate<br>Linearity at 12mW/°C to 200mW |               |
| <b>Device Dissipation per Output Transistor</b>             | .....       | 100mW                                   |               |
| For TA = Full Package Temperature Range (All Package Types) |             |   |               |
| <b>Junction Temperature</b>                                 | .....       | +175°C                                  |               |

**TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER                          | SYMBOL | CONDITIONS (NOTE 1)          | GROUP A<br>SUBGROUPS | TEMPERATURE          | LIMITS      |             | UNITS |    |
|------------------------------------|--------|------------------------------|----------------------|----------------------|-------------|-------------|-------|----|
|                                    |        |                              |                      |                      | MIN         | MAX         |       |    |
| Supply Current                     | IDD    | VDD = 20V, VIN = VDD or GND  | 1                    | +25°C                | -           | 2           | µA    |    |
|                                    |        |                              | 2                    | +125°C               | -           | 200         | µA    |    |
|                                    |        | VDD = 18V, VIN = VDD or GND  | 3                    | -55°C                | -           | 2           | µA    |    |
| Input Leakage Current              | IIL    | VIN = VDD or GND             | VDD = 20             | 1                    | +25°C       | -100        | -     | nA |
|                                    |        |                              |                      | 2                    | +125°C      | -1000       | -     | nA |
|                                    |        |                              | VDD = 18V            | 3                    | -55°C       | -100        | -     | nA |
| Input Leakage Current              | IIH    | VIN = VDD or GND             | VDD = 20             | 1                    | +25°C       | -           | 100   | nA |
|                                    |        |                              |                      | 2                    | +125°C      | -           | 1000  | nA |
|                                    |        |                              | VDD = 18V            | 3                    | -55°C       | -           | 100   | nA |
| Output Voltage                     | VOL15  | VDD = 15V, No Load           | 1, 2, 3              | +25°C, +125°C, -55°C | -           | 50          | mV    |    |
| Output Voltage                     | VOH15  | VDD = 15V, No Load (Note 5)  | 1, 2, 3              | +25°C, +125°C, -55°C | 14.95       | -           | V     |    |
| Output Current (Sink)              | IOL5   | VDD = 5V, VOUT = 0.4V        | 1                    | +25°C                | 0.53        | -           | mA    |    |
| Output Current (Sink)              | IOL10  | VDD = 10V, VOUT = 0.5V       | 1                    | +25°C                | 1.4         | -           | mA    |    |
| Output Current (Sink)              | IOL15  | VDD = 15V, VOUT = 1.5V       | 1                    | +25°C                | 3.5         | -           | mA    |    |
| Output Current (Source)            | IOH5A  | VDD = 5V, VOUT = 4.6V        | 1                    | +25°C                | -           | -0.53       | mA    |    |
| Output Current (Source)            | IOH5B  | VDD = 5V, VOUT = 2.5V        | 1                    | +25°C                | -           | -1.8        | mA    |    |
| Output Current (Source)            | IOH10  | VDD = 10V, VOUT = 9.5V       | 1                    | +25°C                | -           | -1.4        | mA    |    |
| Output Current (Source)            | IOH15  | VDD = 15V, VOUT = 13.5V      | 1                    | +25°C                | -           | -3.5        | mA    |    |
| N Threshold Voltage                | VNTH   | VDD = 10V, ISS = -10µA       | 1                    | +25°C                | -2.8        | -0.7        | V     |    |
| P Threshold Voltage                | VPTH   | VSS = 0V, IDD = 10µA         | 1                    | +25°C                | 0.7         | 2.8         | V     |    |
| Functional                         | F      | VDD = 2.8V, VIN = VDD or GND | 7                    | +25°C                | VOH > VDD/2 | VOL < VDD/2 | V     |    |
|                                    |        | VDD = 20V, VIN = VDD or GND  | 7                    | +25°C                |             |             |       |    |
|                                    |        | VDD = 18V, VIN = VDD or GND  | 8A                   | +125°C               |             |             |       |    |
|                                    |        | VDD = 3V, VIN = VDD or GND   | 8B                   | -55°C                |             |             |       |    |
| Positive Trigger Threshold Voltage | VP5V   | VDD = 5V (Note 2)            | 1, 2, 3              | +25°C, +125°C, -55°C | 2.2         | 3.6         | V     |    |
|                                    | VP15V  | VDD = 15V (Note 3)           | 1, 2, 3              | +25°C, +125°C, -55°C | 6.8         | 10.8        | V     |    |
| Positive Trigger Threshold Voltage | VP5V   | VDD = 5V (Note 4)            | 1, 2, 3              | +25°C, +125°C, -55°C | 2.6         | 4.0         | V     |    |
| Negative Trigger Threshold Voltage | VN5V   | VDD = 5V (Note 2)            | 1, 2, 3              | +25°C, +125°C, -55°C | 0.9         | 2.8         | V     |    |
|                                    | VN15V  | VDD = 15V (Note 3)           | 1, 2, 3              | +25°C, +125°C, -55°C | 4.0         | 7.4         | V     |    |
| Negative Trigger Threshold Voltage | VN5V   | VDD = 5V (Note 4)            | 1, 2, 3              | +25°C, +125°C, -55°C | 1.4         | 3.2         | V     |    |
| Hysteresis Voltage                 | VH5V   | VDD = 5V (Note 2)            | 1, 2, 3              | +25°C, +125°C, -55°C | 0.3         | 1.6         | V     |    |
|                                    | VH15V  | VDD = 15V (Note 3)           | 1, 2, 3              | +25°C, +125°C, -55°C | 1.6         | 5.0         | V     |    |
| Hysteresis Voltage                 | VH5V   | VDD = 5V (Note 4)            | 1, 2, 3              | +25°C, +125°C, -55°C | 0.3         | 1.6         | V     |    |

**NOTES:** 1. All voltages referenced to device GND, 100% testing being implemented.

2. Inputs on terminals 1, 5, 8, 12
3. Input on Terminal 1

- 4. Input on terminals 1 and 2, 5 and 6, 8 and 9, or 12 and 13
- 5. For accuracy, voltage is measured differentially to VDD. Limit

For accuracy, voltage is measured differential to V<sub>DD</sub>. Error is 0.050V max.

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

| PARAMETER         | SYMBOL       | CONDITIONS (NOTES 1, 2)    | GROUP A<br>SUBGROUPS | TEMPERATURE   | LIMITS |     | UNITS |
|-------------------|--------------|----------------------------|----------------------|---------------|--------|-----|-------|
|                   |              |                            |                      |               | MIN    | MAX |       |
| Propagation Delay | TPHL<br>TPLH | VDD = 5V, VIN = VDD or GND | 9                    | +25°C         | -      | 380 | ns    |
|                   |              |                            | 10, 11               | +125°C, -55°C | -      | 513 | ns    |
| Transition Time   | TTHL<br>TTLH | VDD = 5V, VIN = VDD or GND | 9                    | +25°C         | -      | 200 | ns    |
|                   |              |                            | 10, 11               | +125°C, -55°C | -      | 270 | ns    |

## NOTES:

1. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
2. -55°C and +125°C limits guaranteed, 100% testing being implemented.

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

| PARAMETER               | SYMBOL       | CONDITIONS                  | NOTES   | TEMPERATURE          | LIMITS |       | UNITS |
|-------------------------|--------------|-----------------------------|---------|----------------------|--------|-------|-------|
|                         |              |                             |         |                      | MIN    | MAX   |       |
| Supply Current          | IDD          | VDD = 5V, VIN = VDD or GND  | 1, 2    | -55°C, +25°C         | -      | 1     | µA    |
|                         |              |                             |         | +125°C               | -      | 30    | µA    |
|                         |              | VDD = 10V, VIN = VDD or GND | 1, 2    | -55°C, +25°C         | -      | 2     | µA    |
|                         |              |                             |         | +125°C               | -      | 60    | µA    |
|                         |              | VDD = 15V, VIN = VDD or GND | 1, 2    | -55°C, +25°C         | -      | 2     | µA    |
|                         |              |                             |         | +125°C               | -      | 120   | µA    |
| Output Voltage          | VOL          | VDD = 5V, No Load           | 1, 2    | +25°C, +125°C, -55°C | -      | 50    | mV    |
| Output Voltage          | VOL          | VDD = 10V, No Load          | 1, 2    | +25°C, +125°C, -55°C | -      | 50    | mV    |
| Output Voltage          | VOH          | VDD = 5V, No Load           | 1, 2    | +25°C, +125°C, -55°C | 4.95   | -     | V     |
| Output Voltage          | VOH          | VDD = 10V, No Load          | 1, 2    | +25°C, +125°C, -55°C | 9.95   | -     | V     |
| Output Current (Sink)   | IOL5         | VDD = 5V, VOUT = 0.4V       | 1, 2    | +125°C               | 0.36   | -     | mA    |
| Output Current (Sink)   | IOL5         | VDD = 5V, VOUT = 0.4V       |         | -55°C                | 0.64   | -     | mA    |
| Output Current (Sink)   | IOL10        | VDD = 10V, VOUT = 0.5V      | 1, 2    | +125°C               | 0.9    | -     | mA    |
| Output Current (Sink)   | IOL10        | VDD = 10V, VOUT = 0.5V      |         | -55°C                | 1.6    | -     | mA    |
| Output Current (Sink)   | IOL15        | VDD = 15V, VOUT = 1.5V      | 1, 2    | +125°C               | 2.4    | -     | mA    |
| Output Current (Sink)   | IOL15        | VDD = 15V, VOUT = 1.5V      |         | -55°C                | 4.2    | -     | mA    |
| Output Current (Source) | IOH5A        | VDD = 5V, VOUT = 4.6V       | 1, 2    | +125°C               | -      | -0.36 | mA    |
| Output Current (Source) | IOH5A        | VDD = 5V, VOUT = 4.6V       |         | -55°C                | -      | -0.64 | mA    |
| Output Current (Source) | IOH5B        | VDD = 5V, VOUT = 2.5V       | 1, 2    | +125°C               | -      | -1.15 | mA    |
| Output Current (Source) | IOH5B        | VDD = 5V, VOUT = 2.5V       |         | -55°C                | -      | -2.0  | mA    |
| Output Current (Source) | IOH10        | VDD = 10V, VOUT = 9.5V      | 1, 2    | +125°C               | -      | -0.9  | mA    |
| Output Current (Source) | IOH10        | VDD = 10V, VOUT = 9.5V      |         | -55°C                | -      | -1.6  | mA    |
| Output Current (Source) | IOH15        | VDD = 15V, VOUT = 13.5V     | 1, 2    | +125°C               | -      | -2.4  | mA    |
| Output Current (Source) | IOH15        | VDD = 15V, VOUT = 13.5V     |         | -55°C                | -      | -4.2  | mA    |
| Propagation Delay       | TPHL<br>TPLH | VDD = 10V                   | 1, 2, 3 | +25°C                | -      | 180   | ns    |
| Propagation Delay       |              | VDD = 15V                   | 1, 2, 3 | +25°C                | -      | 130   | ns    |
| Transition Time         | TTHL<br>TTLH | VDD = 10V                   | 1, 2, 3 | +25°C                | -      | 100   | ns    |
| Transition Time         |              | VDD = 15V                   | 1, 2, 3 | +25°C                | -      | 80    | ns    |

# Specifications CD4093BMS

**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)**

| PARAMETER                          | SYMBOL | CONDITIONS | NOTES   | TEMPERATURE          | LIMITS |      | UNITS |
|------------------------------------|--------|------------|---------|----------------------|--------|------|-------|
|                                    |        |            |         |                      | MIN    | MAX  |       |
| Positive Trigger Threshold Voltage | VP10V  | VDD = 10V  | 1, 2, 4 | +25°C, +125°C, -55°C | 4.6    | 7.1  | V     |
|                                    | VP10V  | VDD = 10V  | 1, 2, 5 | +25°C, +125°C, -55°C | 5.6    | 8.2  | V     |
|                                    | VP15V  | VDD = 15V  | 1, 2, 5 | +25°C, +125°C, -55°C | 6.3    | 12.7 | V     |
| Negative Trigger Threshold Voltage | VN10V  | VDD = 10V  | 1, 2, 4 | +25°C, +125°C, -55°C | 2.5    | 5.2  | V     |
|                                    | VN10V  | VDD = 10V  | 1, 2, 5 | +25°C, +125°C, -55°C | 3.4    | 6.6  | V     |
|                                    | VN15V  | VDD = 15V  | 1, 2, 5 | +25°C, +125°C, -55°C | 4.8    | 9.6  | V     |
| Hysteresis Voltage                 | VH10V  | VDD = 10V  | 1, 2, 4 | +25°C, +125°C, -55°C | 1.2    | 3.4  | V     |
|                                    | VH10V  | VDD = 10V  | 1, 2, 5 | +25°C, +125°C, -55°C | 1.2    | 3.4  | V     |
|                                    | VH15V  | VDD = 15V  | 1, 2, 5 | +25°C, +125°C, -55°C | 1.6    | 5.0  | V     |
| Input Capacitance                  | CIN    | Any Input  | 1, 2    | +25°C                | -      | 7.5  | pF    |

NOTES:

1. All voltages referenced to device GND.
2. The parameters listed on Table 3 are controlled via design or process and are not directly tested. These parameters are characterized on initial design release and upon design changes which would affect these characteristics.
3. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
4. Input on terminals 1, 5, 8, 12
5. Input on terminals 1 and 2, 5 and 6, 8 and 9, or 12 and 13

**TABLE 4. POST IRRADIATION ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER                 | SYMBOL       | CONDITIONS                  | NOTES      | TEMPERATURE | LIMITS      |                    | UNITS |
|---------------------------|--------------|-----------------------------|------------|-------------|-------------|--------------------|-------|
|                           |              |                             |            |             | MIN         | MAX                |       |
| Supply Current            | IDD          | VDD = 20V, VIN = VDD or GND | 1, 4       | +25°C       | -           | 7.5                | µA    |
| N Threshold Voltage       | VNTH         | VDD = 10V, ISS = -10µA      | 1, 4       | +25°C       | -2.8        | -0.2               | V     |
| N Threshold Voltage Delta | ΔVTN         | VDD = 10V, ISS = -10µA      | 1, 4       | +25°C       | -           | ±1                 | V     |
| P Threshold Voltage       | VTP          | VSS = 0V, IDD = 10µA        | 1, 4       | +25°C       | 0.2         | 2.8                | V     |
| P Threshold Voltage Delta | ΔVTP         | VSS = 0V, IDD = 10µA        | 1, 4       | +25°C       | -           | ±1                 | V     |
| Functional                | F            | VDD = 18V, VIN = VDD or GND | 1          | +25°C       | VOH > VDD/2 | VOL < VDD/2        | V     |
|                           |              | VDD = 3V, VIN = VDD or GND  |            |             |             |                    |       |
| Propagation Delay Time    | TPHL<br>TPLH | VDD = 5V                    | 1, 2, 3, 4 | +25°C       | -           | 1.35 x +25°C Limit | ns    |

NOTES: 1. All voltages referenced to device GND.  
 2. CL = 50pF, RL = 200K, Input TR, TF < 20ns.

3. See Table 2 for +25°C limit.  
 4. Read and Record

# Specifications CD4093BMS

**TABLE 5. BURN-IN AND LIFE TEST DELTA PARAMETERS +25°C**

| PARAMETER               | SYMBOL | DELTA LIMIT                        |
|-------------------------|--------|------------------------------------|
| Supply Current - MSI-1  | IDD    | $\pm 0.2\mu A$                     |
| Output Current (Sink)   | IOL5   | $\pm 20\% \times$ Pre-Test Reading |
| Output Current (Source) | IOH5A  | $\pm 20\% \times$ Pre-Test Reading |

**TABLE 6. APPLICABLE SUBGROUPS**

| CONFORMANCE GROUP             | MIL-STD-883 METHOD | GROUP A SUBGROUPS             | READ AND RECORD                       |
|-------------------------------|--------------------|-------------------------------|---------------------------------------|
| Initial Test (Pre Burn-In)    | 100% 5004          | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| Interim Test 1 (Post Burn-In) | 100% 5004          | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| Interim Test 2 (Post Burn-In) | 100% 5004          | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| PDA (Note 1)                  | 100% 5004          | 1, 7, 9, Deltas               |                                       |
| Interim Test 3 (Post Burn-In) | 100% 5004          | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| PDA (Note 1)                  | 100% 5004          | 1, 7, 9, Deltas               |                                       |
| Final Test                    | 100% 5004          | 2, 3, 8A, 8B, 10, 11          |                                       |
| Group A                       | Sample 5005        | 1, 2, 3, 7, 8A, 8B, 9, 10, 11 |                                       |
| Group B                       | Subgroup B-5       | Sample 5005                   | 1, 2, 3, 7, 8A, 8B, 9, 10, 11, Deltas |
|                               | Subgroup B-6       | Sample 5005                   | 1, 7, 9                               |
| Group D                       | Sample 5005        | 1, 2, 3, 8A, 8B, 9            | Subgroups 1, 2, 3                     |

NOTE: 1. 5% Parameteric, 3% Functional; Cumulative for Static 1 and 2.

**TABLE 7. TOTAL DOSE IRRADIATION**

| CONFORMANCE GROUPS | MIL-STD-883 METHOD | TEST      |            | READ AND RECORD |            |
|--------------------|--------------------|-----------|------------|-----------------|------------|
|                    |                    | PRE-IRRAD | POST-IRRAD | PRE-IRRAD       | POST-IRRAD |
| Group E Subgroup 2 | 5005               | 1, 7, 9   | Table 4    | 1, 9            | Table 4    |

**TABLE 8. BURN-IN AND IRRADIATION TEST CONNECTIONS**

| FUNCTION                   | OPEN         | GROUND            | VDD                        | 9V $\pm$ 0.5V | OSCILLATOR                  |       |
|----------------------------|--------------|-------------------|----------------------------|---------------|-----------------------------|-------|
|                            |              |                   |                            |               | 50kHz                       | 25kHz |
| Static Burn-In 1<br>Note 1 | 3, 4, 10, 11 | 1, 2, 5-9, 12, 13 | 14                         |               |                             |       |
| Static Burn-In 2<br>Note 1 | 3, 4, 10, 11 | 7                 | 1, 2, 5, 6, 8,<br>9, 12-14 |               |                             |       |
| Dynamic Burn-In Note 1     | -            | 7                 | 14                         | 3, 4, 10, 11  | 1, 2, 5, 6,<br>8, 9, 12, 13 | -     |
| Irradiation Note 2         | 3, 4, 10, 11 | 7                 | 1, 2, 5, 6, 8,<br>9, 12-14 |               |                             |       |

NOTES:

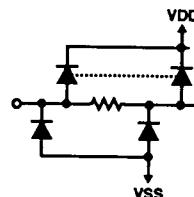
1. Each pin except VDD and GND will have a series resistor of  $10K \pm 5\%$ , VDD =  $18V \pm 0.5V$
2. Each pin except VDD and GND will have a series resistor of  $47K \pm 5\%$ ; Group E, Subgroup 2, sample size is 4 dice/wafer, 0 failures, VDD =  $10V \pm 0.5V$

## Logic Diagram



\* All inputs protected by CMOS protection network

1 OF 4 SCHMITT TRIGGERS



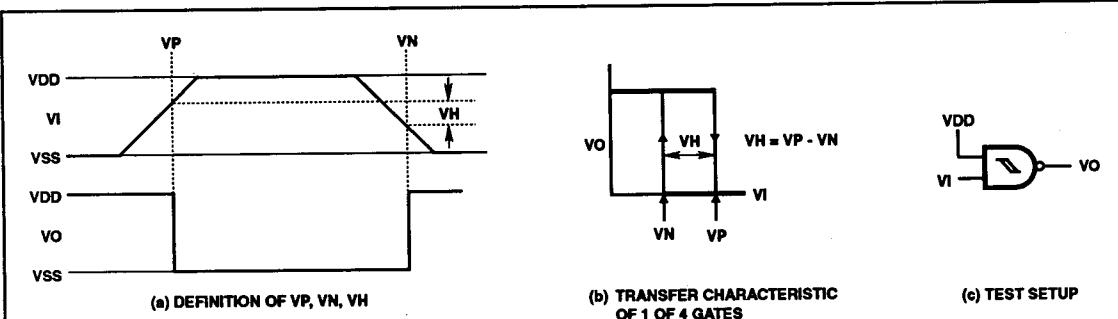


FIGURE 1. HYSTERESIS DEFINITION, CHARACTERISTIC, AND TEST SETUP

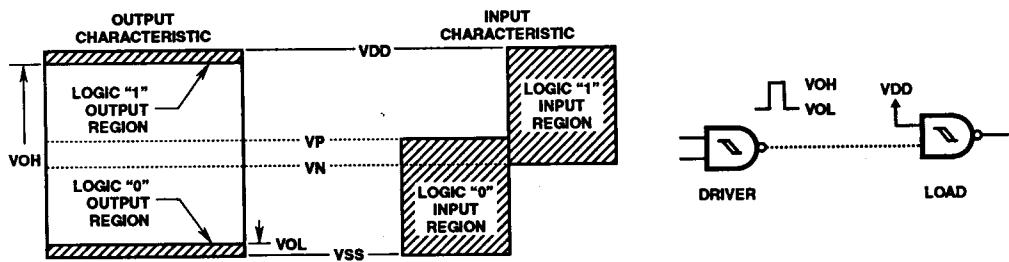


FIGURE 2. INPUT AND OUTPUT CHARACTERISTICS

### Typical Performance Curves

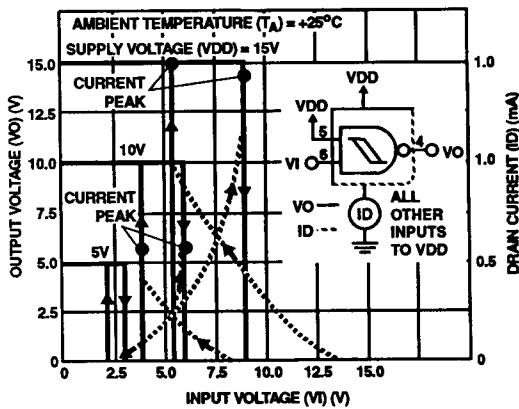


FIGURE 3. TYPICAL CURRENT AND VOLTAGE TRANSFER CHARACTERISTICS

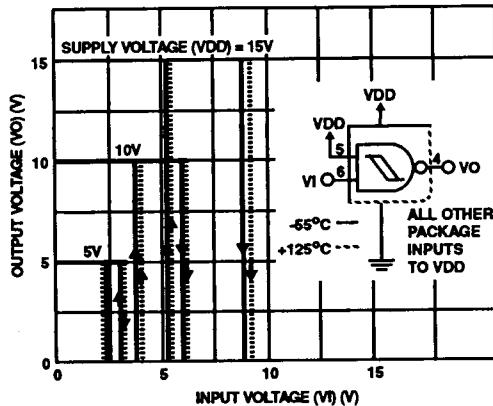


FIGURE 4. TYPICAL VOLTAGE TRANSFER CHARACTERISTICS AS A FUNCTION OF TEMPERATURE

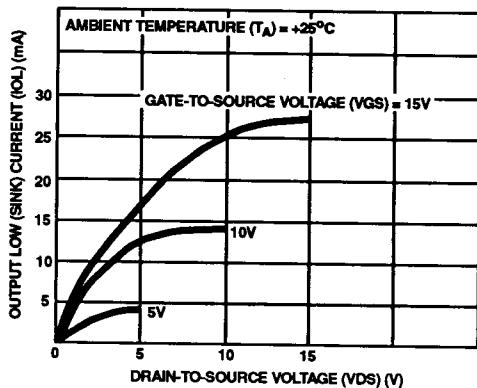
**Typical Performance Curves (Continued)**

FIGURE 5. TYPICAL OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

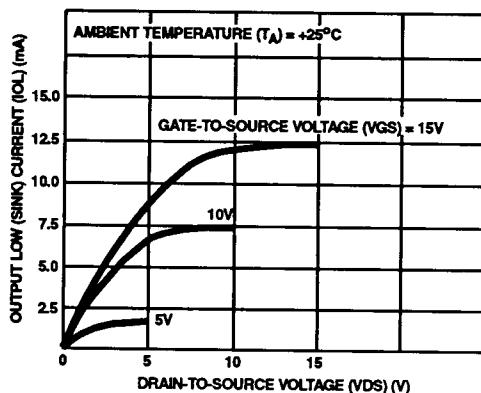


FIGURE 6. MINIMUM OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

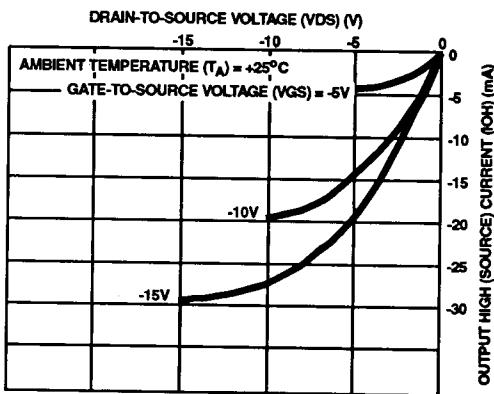


FIGURE 7. TYPICAL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

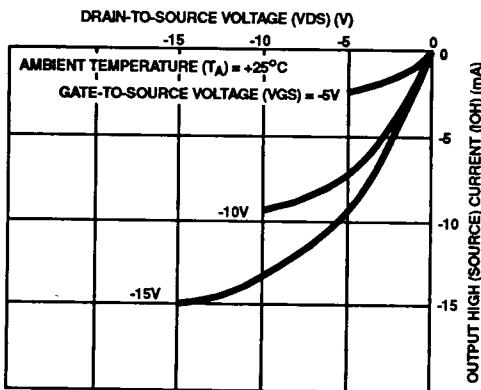


FIGURE 8. MINIMUM OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

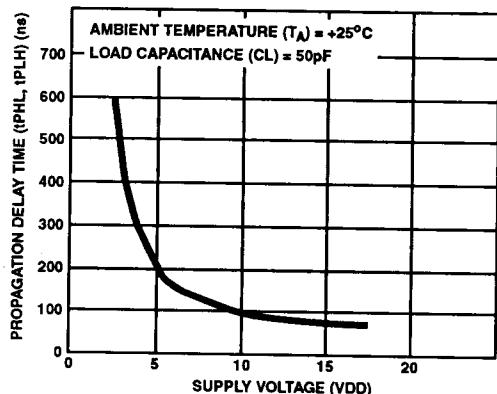


FIGURE 9. TYPICAL PROPAGATION DELAY TIME vs. SUPPLY VOLTAGE

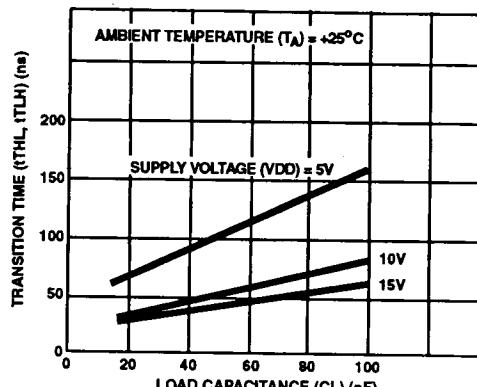


FIGURE 10. TYPICAL TRANSITION TIME vs. LOAD CAPACITANCE

## Typical Performance Curves (Continued)

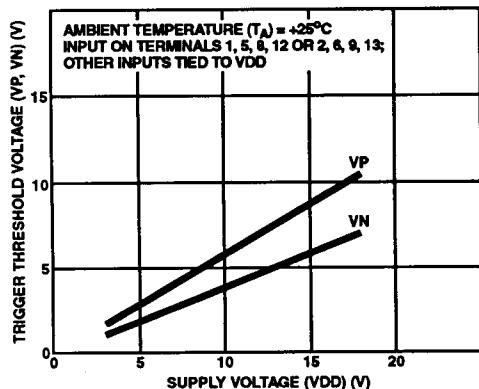


FIGURE 11. TYPICAL TRIGGER THRESHOLD VOLTAGE vs. VDD

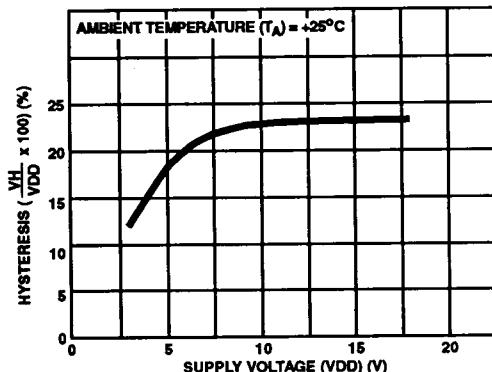


FIGURE 12. TYPICAL PERCENT HYSTERESIS vs. SUPPLY VOLTAGE

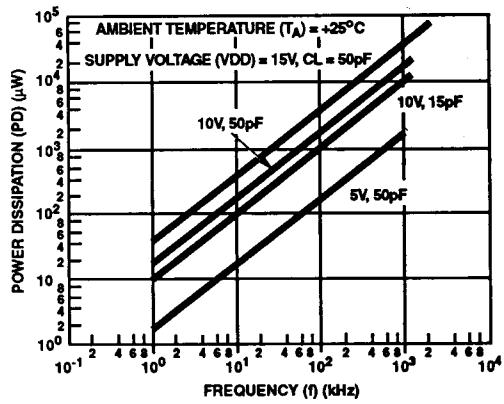


FIGURE 13. TYPICAL POWER DISSIPATION vs. FREQUENCY CHARACTERISTICS

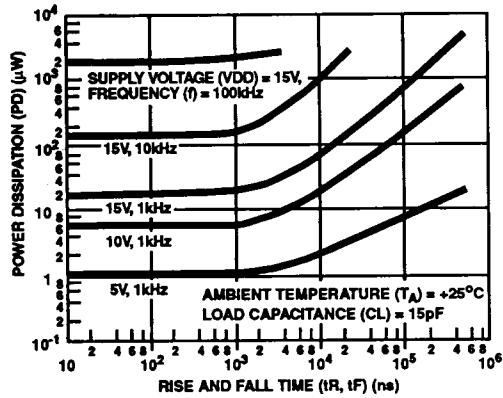


FIGURE 14. TYPICAL POWER DISSIPATION vs. RISE AND FALL TIMES

## Applications

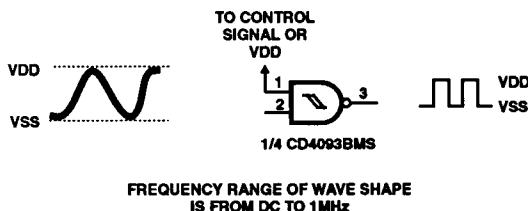


FIGURE 15. WAVE SHAPER

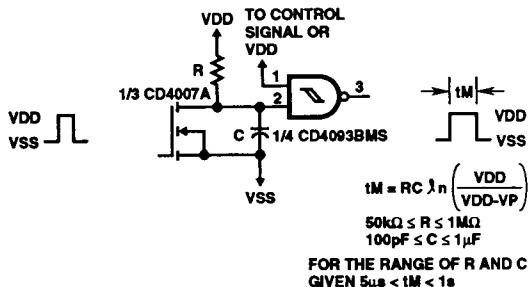


FIGURE 16. MONOSTABLE MULTIVIBRATOR

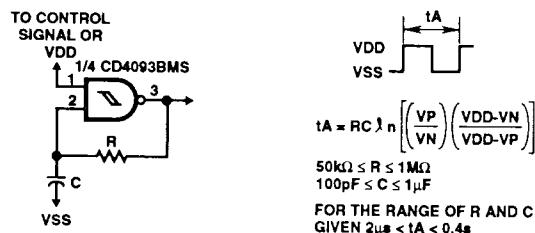
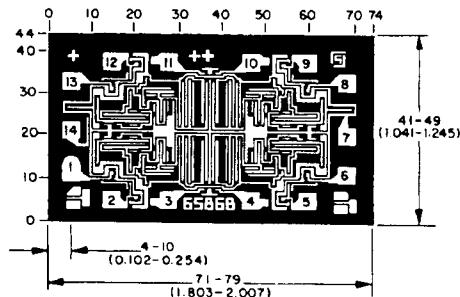
**Applications (Continued)**

FIGURE 17. ASTABLE MULTIVIBRATOR

**Chip Dimensions and Pad Layout**

Dimension in parenthesis are in millimeters and are derived from the basic inch dimensions as indicated.  
Grid graduations are in mils ( $10^{-3}$  inch).

**METALLIZATION:** Thickness:  $11\text{k}\text{\AA} - 14\text{k}\text{\AA}$ , AL.

**PASSIVATION:**  $10.4\text{k}\text{\AA} - 15.6\text{k}\text{\AA}$ , Silane

**BOND PADS:** 0.004 inches X 0.004 inches MIN

**DIE THICKNESS:** 0.0198 inches - 0.0218 inches